

RF CHARACTERISTICS

Frequency range : **0 - 40 GHz**
Impedance : **50 Ohms**

Frequency (GHz)	DC - 6	6 - 12.4	12.4 - 18	18 - 26.5	26.5 - 40
VSWR max	1.30	1.40	1.50	1.70	1.90
Insertion loss max	0.30 dB	0.40 dB	0.50 dB	0.70 dB	0.80 dB
Isolation min	70 dB	60 dB	60 dB	55 dB	50 dB
Average power (*)	80 W	60 W	50 W	20 W	10 W

ELECTRICAL CHARACTERISTICS

Actuator : **LATCHING**
Nominal current ** : **320 mA**
Actuator voltage (Vcc) : **12V (10.2 to 13V)**
Terminals : **solder pins (250°C max. / 30 sec.)**
TTL inputs (E) - High level : **2.2 to 5.5 V / 800µA at 5.5 V**
- Low level : **0 to 0.8 V / 20µA at 0.8 V**

MECHANICAL CHARACTERISTICS

Connectors : **SMA 2.9 female per MIL-C 39012**
Life : **2.5 million cycles**
Switching Time*** : **< 15 ms**
Construction : **Splashproof**
Weight : **< 100 g**

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : **-40°C to +85°C**
Storage temperature range : **-55°C to +85°C**

(* Average power at 25°C per RF Path)

(** At 25° C ±10%)

(*** Nominal voltage ; 25° C)



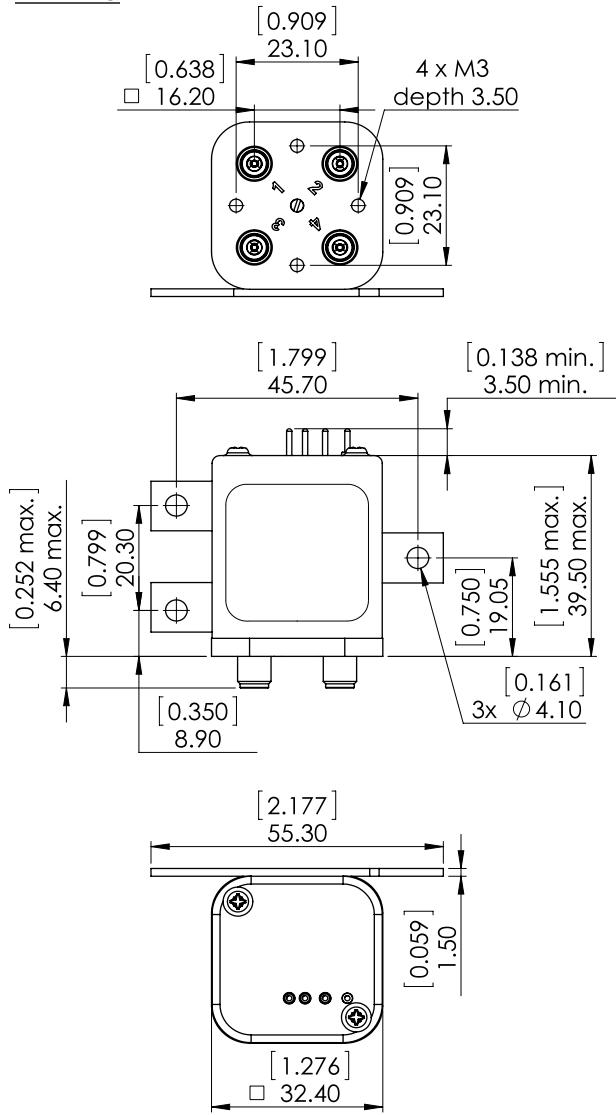
PAGE 2/2

ISSUE 11-04-17

SERIE : DPDT

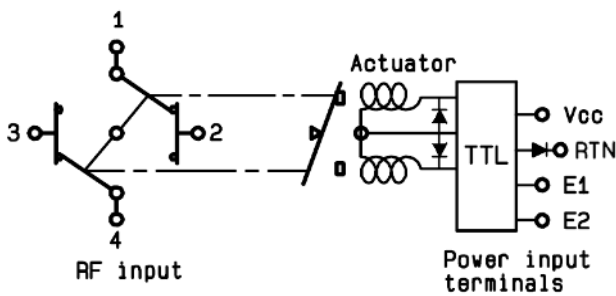
PART NUMBER : R577832100

DRAWING



General tolerances : ±0,5 mm [0,02 in]

SCHEMATIC DIAGRAM



LABEL

E1 E2 GND Vcc

RADIALL®
R577832100
0 - 40 GHz
Un : 12V
Lot : _ _ _ _

TTL input	RF Continuity
E1=1 / E2=0	1 ↔ 3 / 2 ↔ 4
E1=0 / E2=1	1 ↔ 2 / 3 ↔ 4
E1=0 / E2=0	Memory
E1=1 / E2=1	Forbidden